

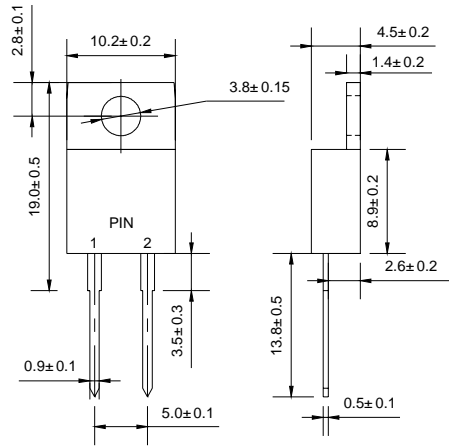


REVERSE VOLTAGE: 20 - 60 V
FORWARD CURRENT: 16 A

Features

- ◇ Metal-Semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ For use in low voltage,high frequency inverters free wheeling,and polarity protection applications
- ◇ Low forward voltage drop,low switching losses
- ◇ High surge capability
- ◇ The plastic material carries U/L recognition 94V-0

TO-220AC



Dimensions in millimeters

Mechanical Data

- ◇ Case:JEDEC TO--220AC,molded plastic
- ◇ Polarity: As marked
- ◇ Weight: 0.064 ounce, 1.81 grams
- ◇ Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

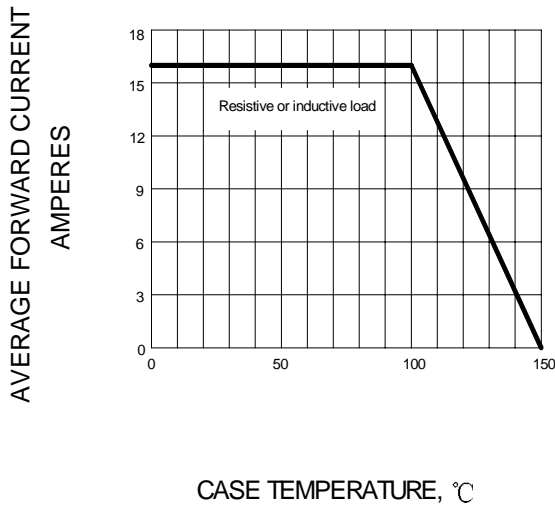
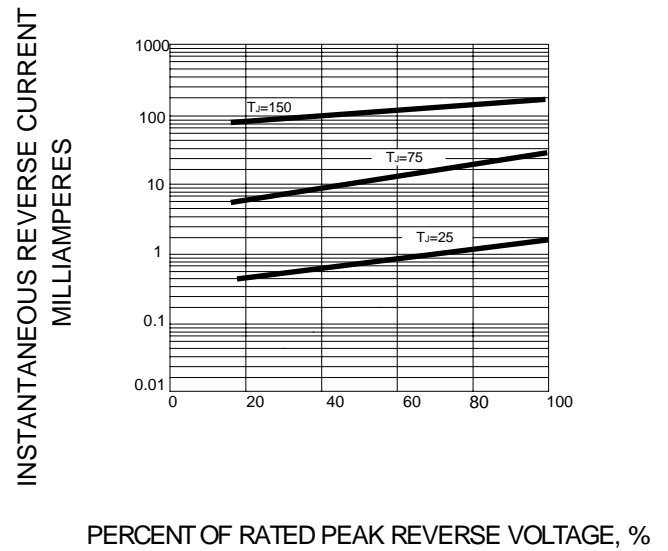
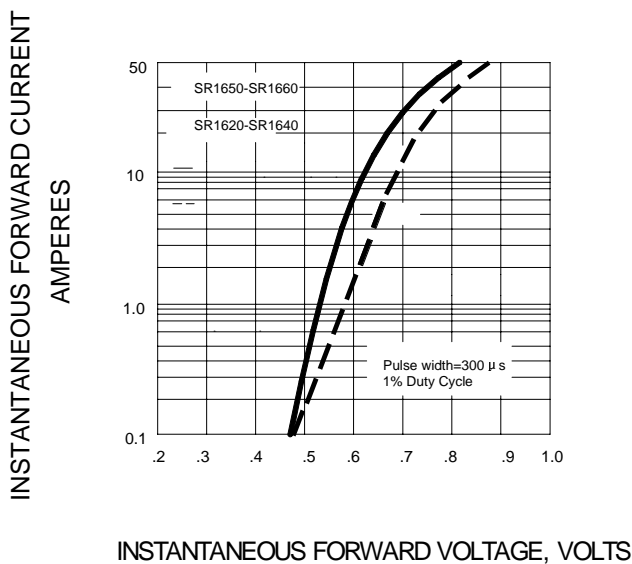
Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		SR 1620	SR 1630	SR 1640	SR 1650	SR 1660	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	20	30	40	50	60	V
Working peak reverse voltage	V_{RMS}	14	21	28	35	42	V
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	V
Maximum average forward rectified current @ $T_A=100^\circ\text{C}$	$I_{F(AV)}$	16.0					A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method) @ $T_J=125^\circ\text{C}$	I_{FSM}	200.0					A
Maximum instantaneous forward voltage per leg @ 16A (Note1)	V_F	0.7			0.8		V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	1.0 50.0					mA
Operating junction temperature range	T_J	-55 --- +150					°C
Storage temperature range	T_{STG}	-55 --- +150					°C

Note: 1. Pulse test:300us pulse width,1% duty cycle.

Ratings AND Characteristic Curves

FIG.1 – FORWARD CURRENT DERATING CURVE

FIG.2 – TYPICAL REVERSE CHARACTERISTICS

FIG.3 – TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

FIG.4 – PEAK FORWARD SURGE CURRENT
